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Stability Region Exploring of Shunt Active Power Filters Based on Output Admittance Modeling

Jintao Lei, *Student Member, IEEE*, Zian Qin, *Senior Member, IEEE*, Wuhua Li, *Member, IEEE*, Pavol Bauer, *Senior Member, IEEE* and Xiangning He, *Fellow, IEEE*

Abstract—Shunt Active Power Filter (SAPF) is coupled with load admittance in weak grid conditions, which poses a challenge to stability analysis. In this paper, the admittance model of the SAPF is developed, which reveals the coupling mechanism between SAPF and load concisely and accurately. On top of that, the stability region of the system is investigated. Passivity region of the load admittance to guarantee the system stability is firstly explored. However, Passivity region has very narrow band at a specific frequency, which makes it difficult to achieve. Stability region is then studied and it turns out to be an extension of the passivity region, and especially the narrow band is expanded. Therefore the stability region is much easier to meet. The stability-oriented design is then summarized in a flow chart. In the end, the effectiveness of the newly defined stability region is verified by experimental results.

Keywords—active power filters, stability, admittance, modeling

I. INTRODUCTION

POWER electronics, which is used at both the generation and demand sides for high conversion efficiency, is experiencing a rapid growth [1-4]. Dc grid technology was proposed in recent years, which has the advantage of effectively integrating those dc power sources and loads. Despite this, the ac grid is still dominating the power system. In the ac grid, most of the electrical loads like adjustable speed drives, power supplies, electrolyzers, etc. [5, 6], have a front-end rectifier to convert AC grid voltage to DC voltage to fulfill the requirement of the loads. The rectifiers, especially the passive ones, cause significant power quality (PQ) issues, in terms of harmonic currents [7, 8]. The harmonic currents cause more cable loss, lead to grid voltage distortion and thereby speed up the aging of the cable and transformer insulators, etc. Moreover, it degrades the performance of the protection equipment in the power system, e.g., relays, circuit breakers, etc.

According to the utility harmonic standards, such as IEEE Standard 519-1992 and IEC Standard 61000-3-6, the total

harmonic distortion (THD) in the current of the grid-connected device should be lower than 5%. To fulfill the standard, passive RLC power filters (PPFs), are widely used in demand-side and distribution system [9, 10]. However, the PPFs have significant drawbacks, including heavyweight, non-flexibility, self-resonance, etc. In contrast, the shunt active power filter (SAPF) has been proved to be a superior solution for harmonics current mitigation due to its smaller size, better dynamic performance, and more flexibility [11, 12]. Since SAPF is used for compensating load harmonic currents, it is common to simplify the load into a harmonic current source in the modeling of SAPF [13-16]. Research effort has been mainly put on current control strategies [17-22], topologies [23-25], and reference current extraction methods [26-28] to enhance the harmonic compensation performance. It takes for granted to consider SAPF to be in favor of system stability by eliminating harmonic currents. However, it might not be true when the load dynamic is not taken into consideration.

The impact of SAPF on grid stability has been studied in a few pieces of literature. A new model for SAPF was proposed in [29], where the influence of the load and grid impedance were considered. On top of the proposed SAPF model, stability analysis was performed, and a damping approach was applied to suppress resonance. Yet, SAPF was modeled as a voltage source in series with an *LCL* filter, which has some gap with reality. The model was further developed in [30], where the interaction between the load and APF was considered into one integrated model. However, all effects are coupled together, so it is challenging to study the influence of load and SAPF individually. A Lyapunov stability theory-based control method was proposed for a three-level SAPF in [31], which does not rely on linearization of the system. However, with the minimal details provided in the literature, it is hard to tell how the control and load influence the stability.

Impedance based approach has been proved to be useful in analyzing the interactions of converters [32-34]. Among the different small-signal methods for stability analysis of power electronics-based grid, the impedance-based approach is superior in terms of design-oriented analysis, modularity, and scalability [35, 36]. Therefore, to reveal the impact of SAPF on the stability of the grid, a concise and accurate SAPF output admittance model was developed in our previous work [37], considering the influence of the load dynamic. In this paper, the admittance modelling is presented in a more concise way. More importantly, based on the developed admittance model of SAPF, the stability region of the system is investigated. Passivity region of the load admittance to guarantee the system

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stability is firstly explored. However, Passivity region has very strict boundary conditions, which are difficult to achieve in reality. Stability region is then studied and it turns out to have much less strict boundary conditions, and thereby much easier to fulfill. The stability region defined in this paper provides a guide to SAPF for valid application scenarios, where accurate admittance model of the load is not required, instead a rough knowledge of the admittance is sufficient to judge the stability of the system. A stability-oriented design is summarized in a flow chart. The rest of this paper is organized as follows: in Section II, the modeling of SAPF takes the load dynamics into account, and a frequency-sweep verifies it; Section III explores the stability region based on the developed admittance model; Section IV performs the experimental validation; Section V concludes the paper.

II. IMPEDANCE MODELING

A. Modeling

Fig.1 shows a three-phase grid-connected system, including the load, SAPF, and grid. The grid is simplified into a voltage source V_g in series with impedance $Z_g(s)$ that composed of L_g and R_g . The load and SAPF are connected to the Point of Common Coupling (PCC), where the voltage is defined as V_{pcc} , in parallel. In SAPF, an LCL filter composed of L_1 , L_2 , and C_f is applied to achieve a relatively smaller filter size and the voltage near the inverter side is defined as V_{inv} . The control diagram of the SAPF is shown in Fig. 2. To compensate for the harmonic items in the load current, the load current I_L is firstly measured. Then by employing a high pass filter $G_{hp}(s)$, the harmonic items in I_L are extracted. Since the positive direction of I_L is defined as from load to grid, the current reference I_{ref} of the current controller in SAPF has the same amplitude as harmonic items in I_L but in the opposite phase. Note that the control of dc-link voltage V_{dc} and phase-locked loop (PLL), are not considered. As known, the dc-link voltage control loop mainly influences the subsynchronous frequency, while the PLL affects the above and near the synchronous frequency [38, 39]. This paper will focus on the medium frequency, where the current control loop dominates.

To achieve zero error tracking at harmonic frequencies, Quasi-PR compensator with multi resonant frequencies can be applied, as $G_c(s)$ in Fig. 2 (a) and it is defined as

$$G_c(s) = K_p + \sum_{h=5,7,11,13,\dots} \frac{\frac{2K_{rh}h\omega_g}{Q}s}{s^2 + \frac{2h\omega_g}{Q}s + h^2\omega_g^2} \quad (1)$$

where $\omega_g=2\pi f_g$ is the fundamental angular frequency, K_p is proportional gain and K_{rh} is the gain at harmonic order h , Q is the quality factor. The time delay of the control loop is defined as

$$G_d(s) = e^{-1.5T_s s} \quad (2)$$

where T_s is the sampling period, and symmetrical sampling is applied. The output LCL filter has two critical frequencies, f_{r1} and f_{r2} , defined as

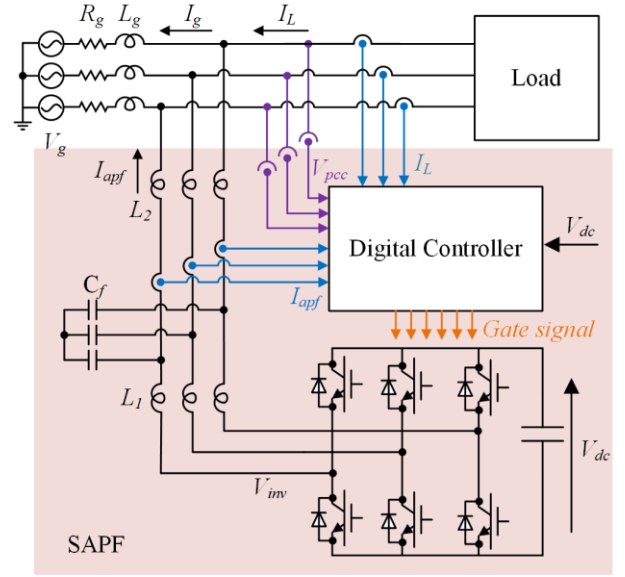


Fig. 1. A shunt active power filter together with load and grid.

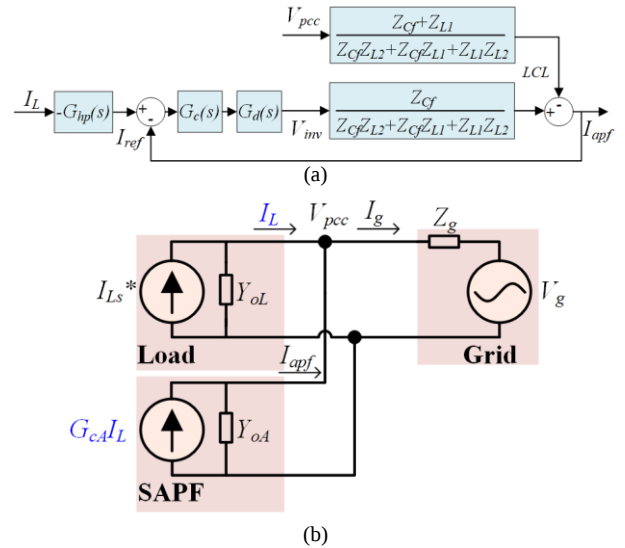


Fig. 2. (a) control diagram of SAPF, (b) equivalent circuit of the system.

$$f_{r1} = \frac{1}{2\pi\sqrt{L_1 C_f}} \quad (3)$$

$$f_{r2} = \frac{1}{2\pi\sqrt{L_2 L_1 C_f}} \quad (4)$$

The close loop gains $G_{cA}(s)$ and output admittance $Y_{oA}(s)$ of SAPF can be easily derived from the control diagram in Fig.2, and they are

$$G_{cA}(s) = \frac{-G_{hp}(s)T_a(s)}{1 + T_a(s)} \quad (5)$$

$$Y_{oA}(s) = \frac{Y_a(s)}{1 + T_a(s)} = \frac{1}{\frac{1}{Y_a(s)} + \frac{T_a(s)}{Y_a(s)}} \quad (6)$$

where

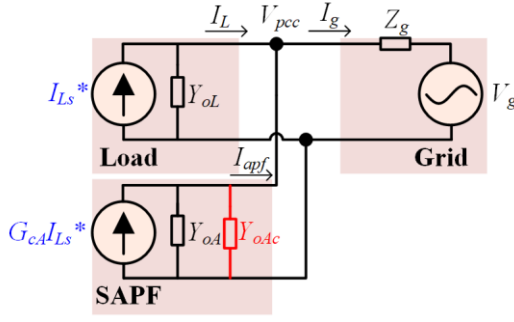


Fig. 3. Proposed impedance model of SAPF (with coupling admittance from the load) and the whole system.

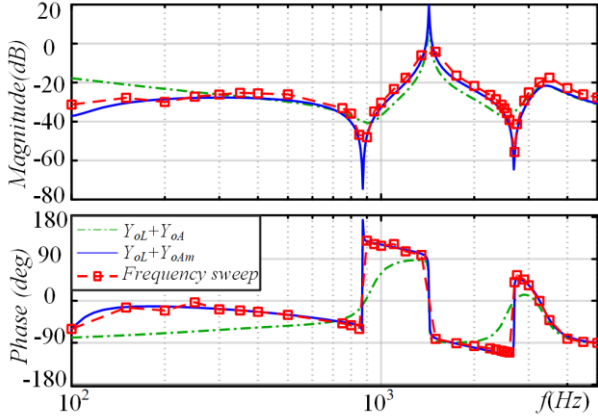


Fig. 4. Analytical admittance and frequency sweep results.

$$T_a(s) = \frac{G_c(s)G_d(s)Z_{cf}}{Z_{L1}Z_{L2} + Z_{L1}Z_{cf} + Z_{L2}Z_{cf}} \quad (7)$$

$$Y_a(s) = \frac{Z_{cf} + Z_{L1}}{Z_{L1}Z_{L2} + Z_{L1}Z_{cf} + Z_{L2}Z_{cf}} \quad (8)$$

Z_{L1} , Z_{L2} and Z_{cf} are the impedance of L_1 , L_2 and C_f branches in SAPF filter, respectively.

The system in Fig. 1 is then indicated as an impedance model, as shown in Fig. 2(b). Besides the output admittance of SAPF, the output admittance of the load Y_{oL} is also considered. As seen, the current source in the SAPF model is dependent on the load current, while the load current I_L can be depicted as,

$$I_L = I_{Ls}^* - Y_{oL}(s)V_{PCC} \quad (9)$$

where I_{Ls}^* is equivalent current source of load according to Norton principle. The current source in SAPF model then becomes

$$G_{CA}(s)I_L = G_{CA}(s)I_{Ls}^* - G_{CA}(s)Y_{oL}(s)V_{PCC} \quad (10)$$

whose second item is also an admittance. Therefore, the output admittance of the SAPF turns out to be

$$Y_{oAm}(s) = Y_{oA}(s) + Y_{oAc}(s) = Y_{oA}(s) - G_{CA}(s)Y_{oL}(s) \quad (11)$$

This extra item $Y_{oAc}(s)$ reflects the coupling between SAPF and load, and it also influences system stability. Meanwhile, the impedance model of SAPF and the system are modified from Fig. 2(b) to Fig. (3). According to the impedance stability

criteria [32], the system stability is determined by $T(s)$ defined as

$$T(s) = Z_g(s)[Y_{oAm}(s) + Y_{oL}(s)] \quad (12)$$

B. Frequency sweep

To further verify the accuracy of the proposed model, a frequency-sweep of the SAPF and load output admittance is carried out. Due to the coupling between load and SAPF, output admittances of them are considered as a whole instead of individually. The parameters for load and SAPF in Case I in Table II are used, and the Grid impedance Z_g is set to be zero. A small perturbation is injected into the grid voltage V_g . Then, the total equivalent output admittance of SAPF and load can be calculated as a ratio between the grid voltage and current perturbation.

Fig. 4 shows the admittance obtained from frequency sweep and the proposed admittance, which match each other very well. To indicate the impact of the coupling admittance, another admittance w/o the coupling admittance is also shown as the dashed curve. A significant error between it and the frequency sweep result is observed.

III. STABILITY REGION

Based on the proposed model, system stability can be easily analyzed if the load admittance and grid impedance are both known. Yet, in reality, the impedance of a distributed system is time-variant and thereby is challenging to measure accurately. The load admittance is not easy to measure precisely, neither. Therefore, in this section, the passivity region and stability region for load admittance are explored, where a specific and precise load admittance is not necessary for stability analysis.

A. Passivity criterion

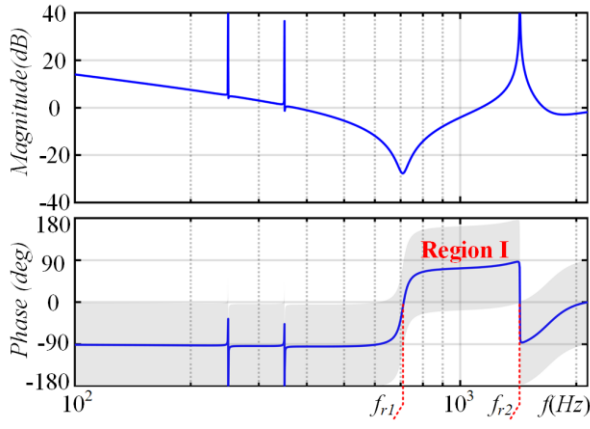
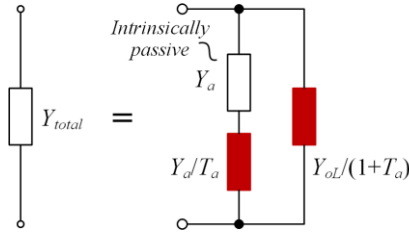
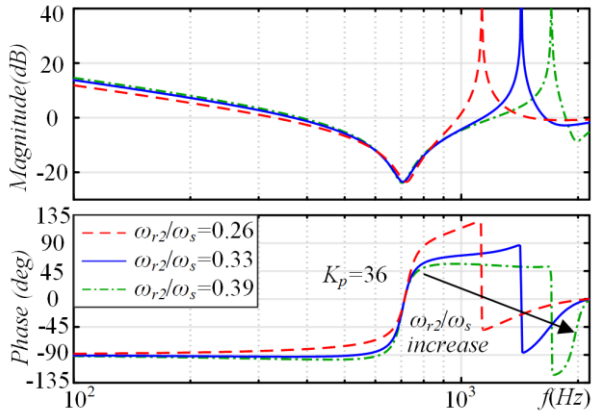
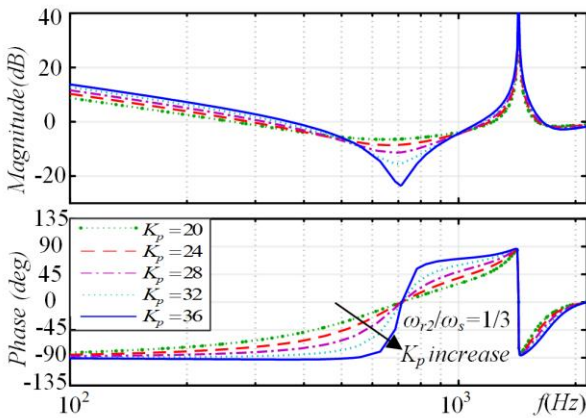
As known, the grid is usually considered to be intrinsically passive. Thus, according to the passivity criteria [40], the stability of the system is determined by load and SAPF. As long as the summation of these two output admittance is passive, the system is stable. To be passive, the total output admittance $Y_{total}(s)$ must meet two requirements as follows,

- $Y_{total}(s)$ has no Right-Half-Plane (RHP) pole
- $\text{Re}\{Y_{total}(j\omega)\} \geq 0 \Leftrightarrow \arg\{Y_{total}(j\omega)\} \in [-90^\circ, 90^\circ], \forall \omega > 0$

According to [41], the paralleled or series-connection of several passive systems is still passive. From the impedance model of the system shown in Fig. 3, the total output admittance is easily obtained as (13), which consists of two parts. The first part, $Y_{oA}(s)$, is solely determined by SAPF itself. The second part, $-G_{CA}(s)Y_{oL}(s) + Y_{oL}(s)$, is affected by both load output admittance and SAPF design. The high pass filter $G_{hp}(s)$ in $G_{CA}(s)$ for the reference current extraction can be simplified to 1 above the fundamental frequency. Then substituting (5), and (6) into (13), (14) is obtained.

$$Y_{total}(s) = Y_{oA}(s) - G_{CA}(s)Y_{oL}(s) + Y_{oL}(s) \quad (13)$$

$$Y_{total}(s) = Y_{oA}(s) + \frac{1}{1 + T_a(s)} Y_{oL}(s) = \frac{Y_a(s) + Y_{oL}(s)}{1 + T_a(s)} \quad (14)$$


 Fig. 5. Bode plot of $1+T_a(s)$

 Fig. 6. Decomposition of Y_{total}

 Fig. 7. Bode plot of $1+T_a(s)$ with different ω_{r2}/ω_{r1}

 Fig. 8. Bode plot of $1+T_a(s)$ with different K_p

For $Y_{total}(s)$, its denominator, $1+T_a(s)$, is determined by SAPF and should have no RHP zero, otherwise, SAPF itself will be unstable no matter what the grid or load condition is. When the phase difference between $Y_a(j\omega)+Y_{ol}(j\omega)$ and

$1+T_a(j\omega)$ is less than 90 degrees, the real part of $Y_{total}(s)$ will be positive and thereby $[Y_a(s)+Y_{ol}(s)]/[1+T_a(s)]$ is passive. That is to say, the phase of $Y_a(s)+Y_{ol}(s)$ should locate in the shadow region (Region I) illustrated in Fig. 5. The Region I is flexible and it can be adjusted to fit $Y_a(s)+Y_{ol}(s)$ by changing parameters of SAPF, such as resonant frequencies f_{r1} and f_{r2} of its LCL filter, sampling frequency f_s , proportional gain K_p , etc. More explanation is as follows.

B. Passivity region

According to (14), $Y_{total}(s)$ can be decomposed into three admittances, as shown in Fig. 6. $Y_{total}(s)$ will be passive if these three admittances are individually passive. $Y_a(s)$, as illustrated in (8), is intrinsically passive because it is a network composed of RLC components. The other two items have the open-loop transfer function $T_a(s)$ involved, thus might be active and need further analysis as follows. According to (3), (7) and (8), it can be obtained,

$$\frac{Y_a(s)}{T_a(s)} = \frac{Z_{Cf} + Z_{L1}}{G_c(s)G_d(s)Z_{Cf}} = \frac{L_1 C_f (\omega_{r1}^2 + s^2)}{G_c(s)G_d(s)} \quad (15)$$

Due to the resonant item of the compensator $G_c(s)$, $|1+T_a| \gg 1$ at resonant frequencies. Therefore according to (12) and (14), the open loop transfer function which determines the stability of the system $|T(s)| \ll 1$ at resonant frequencies. It means the Nyquist curve of $T(s)$ will not cross -180 degree from the left side of (-1,0) at the resonant frequencies. Meanwhile the resonant part of $G_c(s)$ influences only near the resonant frequencies as long as the quality factor Q is high. Thus the resonant part in $G_c(s)$ will not influence the system stability. The resonant part can still affect the loop gain of the APF and lead to instability. However, as the issue has been studied a lot in literature, it is not discussed here. The analysis in this paper is based on assumption that the loop gain of the APF has no stability issue with a proper design. Therefore, only the proportional gain K_p of the compensator is considered for simplicity. It is then obtained,

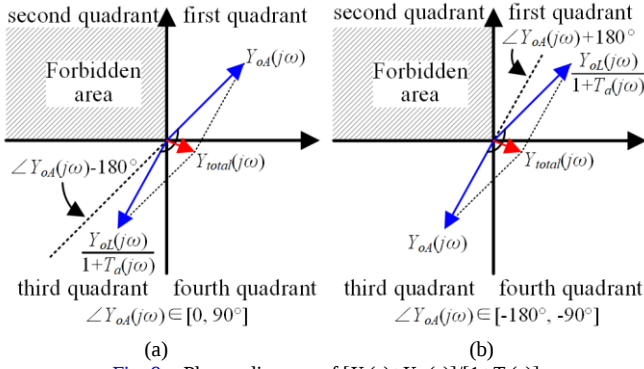
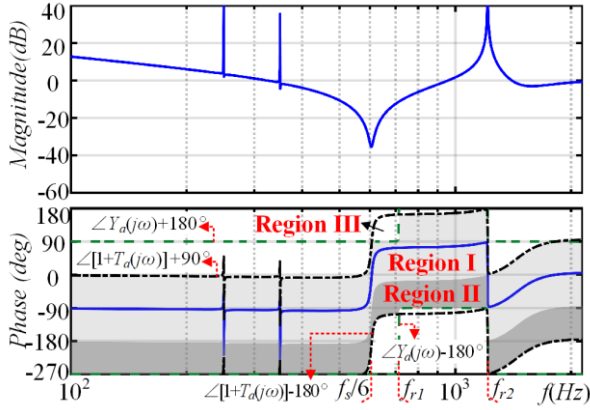
$$\frac{Y_a(j\omega)}{T_a(j\omega)} = \frac{L_1 C_f (\omega_{r1}^2 - \omega^2) [\cos(1.5\omega T_s) + j \sin(1.5\omega T_s)]}{K_p} \quad (16)$$

When the resonant frequency f_{r1} is equal to 1/6 of sampling frequency f_s , the real part of (16) will never be negative within the Nyquist frequency range and therefore $Y_a(s)/T_a(s)$ is passive.

As for the last term $Y_{ol}(s)/[1+T_a(s)]$, $Y_{ol}(s)$ is independent from $1+T_a(s)$. Hence, it can be passive when the phase difference between $Y_{ol}(s)$ and $1+T_a(s)$ is in $[-90^\circ, 90^\circ]$, which is exactly the Region I in Fig. 5. Therefore, Region I is also called the passivity region and can be changed to fit the load output admittance $Y_{ol}(s)$.

For those loads that is capacitive in only one frequency range, f_{r1} and f_{r2} should be set at the lower and upper limit of this frequency range, respectively. Meanwhile, the sampling frequency f_s is always set to be $6 f_{r1}$. The passivity region around the resonant frequencies of $G_c(s)$ might be narrow and thereby difficult to cover $Y_{ol}(s)$, however as mentioned above, the resonant item in $G_c(s)$ will not influence the stability of the system. More flexibility of the passivity region is discussed as follows.

As shown in Fig. 7, the phase angle for $1+T_a(s)$ near f_{r2} varies with the ratio of frequency f_{r2} and f_s . In this way, it can be


 Fig. 9. Phasor diagram of $[Y_a(s) + Y_{oL}(s)]/[1 + T_a(s)]$

 Fig. 10. Bode plot of $1 + T_a(s)$ with an expanded region

adjusted to fit the loads. $1 + T_a(s)$ near f_{r2} can be calculated as follows according to (7),

$$1 + T_a(j\omega)|_{\omega \rightarrow \omega_{r2}} = 1 + \frac{K_p e^{-1.5j\omega_{r2}T_s}}{L_1 L_2 C_f j\omega(-\omega^2 + \omega_{r2}^2)} \quad (17)$$

whose phase angle is then obtained as,

$$\angle[1 + T_a(j\omega)|_{\omega \rightarrow \omega_{r2}}] = \begin{cases} \frac{\pi}{2} \left(-\frac{6\omega_{r2}}{\omega_s} + 3 \right), & \text{if } \omega < \omega_{r2} \\ \frac{\pi}{2} \left(-\frac{6\omega_{r2}}{\omega_s} + 1 \right), & \text{if } \omega > \omega_{r2} \end{cases} \quad (18)$$

As seen, if the ratio of f_{r2} and f_s is 1/3, the phase jump from 90° to -90° at f_{r2} , which makes the passivity region easier to cover $Y_{oL}(s)$.

In addition, the proportional gain K_p , mainly related to the phase change per frequency, as shown in Fig.8, can be lower to smooth the phase near f_{r1} . Moreover, active or passive damping can be applied to restrain the dramatic phase jump near f_{r2} , leading to the connection of two parts of Region I.

C. Stability region

However, the passive criterion is hard to meet because of the strict requirements. The passive criterion is a sufficient but not necessary condition for stability. The stability region, which is less conservative and more practical, is then analyzed as follows.

According to (12) and (14), $T_m(s)$ that determines the stability of the system becomes,

$$T_m(s) = Z_g(s)Y_{total}(s) = \frac{Z_g(s)[Y_a(s) + Y_{oL}(s)]}{1 + T_a(s)} \quad (19)$$

The system will be stable, as long as the phase of $T_m(s)$ stays in $[-180^\circ, 180^\circ]$. According to (19), $T_m(s)$ is comprised of $Y_{total}(s)$ and $Z_g(s)$ and their phase relationship is as follow,

$$\angle T_m(j\omega) = \angle Z_g(j\omega) + \angle Y_{total}(j\omega) \quad (20)$$

In most of the scenarios, the grid impedance $Z_g(s)$ is inductive and thus its phase is between 0 and 90° . Then, to ensure that $\angle T_m(j\omega)$ is within the required range for any inductive grid impedance, the allowed phase range for $Y_{total}(j\omega)$ is $[-180^\circ, 90^\circ]$.

To depict the stability region for load admittance solely, the total output admittance $Y_{total}(s)$ is decomposed into two parts, $Y_{oA}(s)$ and $Y_{oL}(s)/[1 + T_a(s)]$, conforming to (14). Even the phase of both parts is in $[-180^\circ, 90^\circ]$, is not a sufficient condition because the sum of two vectors, one in the first quadrant and another in the third quadrant, is possible to be in the second quadrant. More details are discussed as follows.

For the first item $Y_{oA}(s)$, if the switching frequency f_s is set to $6f_{r1}$, $Y_{oA}(s)$ is passive according to the analysis in Section III-B. But it is difficult to realize due to the parameter variation of LCL elements. In light of (3), (4), (7) and (8), $Y_a(j\omega)$ and $1 + T_a(j\omega)$ can be written as

$$Y_a(j\omega) = j \frac{(\omega^2 - \omega_{r1}^2)}{L_2 \omega(\omega_{r2}^2 - \omega^2)} \quad (21)$$

$$1 + T_a(j\omega) = 1 - \frac{K_p \sin(1.5\omega T_s)}{L_1 L_2 C_f \omega(\omega_{r2}^2 - \omega^2)} - \frac{jK_p \cos(1.5\omega T_s)}{L_1 L_2 C_f \omega(\omega_{r2}^2 - \omega^2)} \quad (22)$$

First of all, to accurately control the grid current, SAPF will apply a grid current feedback control. Therefore, $f_{r2} > f_s/6$ should be ensured to make the SAPF stable itself.

a) $f_{r1} < f_s/6$. The phase of $Y_a(j\omega)$ in the range $[f_{r1}, f_s/6]$ is 90° , while $1 + T_a(j\omega)$ is in the fourth quadrant where its phase is smaller than zero. Thus, $Y_{oA}(j\omega)$ will be in the second quadrant.

b) $f_s/6 < f_{r1}$. The phase of $Y_a(j\omega)$ is the range $[f_s/6, f_{r1}]$ is -90° , while $1 + T_a(j\omega)$ is in the first quadrant. Thus, $Y_{oA}(j\omega)$ will be in the third quadrant. Similarly, in the range $[0, f_s/6]$, $Y_{oA}(j\omega)$ will be in the fourth quadrant, in the range $[f_{r1}, f_s/2]$, $Y_{oA}(j\omega)$ will be in the first quadrant.

Consequently, $f_s/6 \leq f_{r1}$ will be a necessary condition.

For $Y_{oA}(j\omega)$ locating in the first quadrant, the phase of $Y_{oL}(j\omega)/[1 + T_a(j\omega)]$ should be within $[\angle Y_{oA}(j\omega) - 180^\circ, 90^\circ]$ as illustrated in Fig.9 (a). Otherwise, $Y_{total}(j\omega)$ will easily enter the forbidden region when the magnitude of $Y_{oL}(j\omega)/[1 + T_a(j\omega)]$ is large. Similarly, for $Y_{oA}(j\omega)$ locating in the third quadrant, the phase of $Y_{oL}(j\omega)/[1 + T_a(j\omega)]$ should be within $[-180^\circ, \angle Y_{oA}(j\omega) + 180^\circ]$ as depicted in Fig.9 (b).

For $Y_{oA}(j\omega)$ locates in the fourth quadrant, then as long as $Y_{oL}(j\omega)/[1 + T_a(j\omega)]$ is not in the second quadrant, $Y_{total}(j\omega)$ will never enter the forbidden region.

From the analysis above, the limitation of $Y_{oL}(j\omega)$ phase then can be derived as (23).

$$\begin{aligned} \angle Y_{oL}(j\omega) &\in [\angle Y_a(j\omega) - 180^\circ, \angle Y_a(j\omega) + 180^\circ] \\ &\cap [\angle[1 + T_a(j\omega)] - 180^\circ, \angle[1 + T_a(j\omega)] + 90^\circ] \end{aligned} \quad (23)$$

Then, the region expands from Region I to Region I + Region II – Region III as depicted in Fig.10, namely stability region. If the switching frequency f_s is equal to $6f_{r1}$, Region III will be zero. Moreover, the stability region is continuous at f_{r2} , which is however not the case for the passivity region.

TABLE I. COMPARISON OF PASSIVITY AND STABILITY REGION.

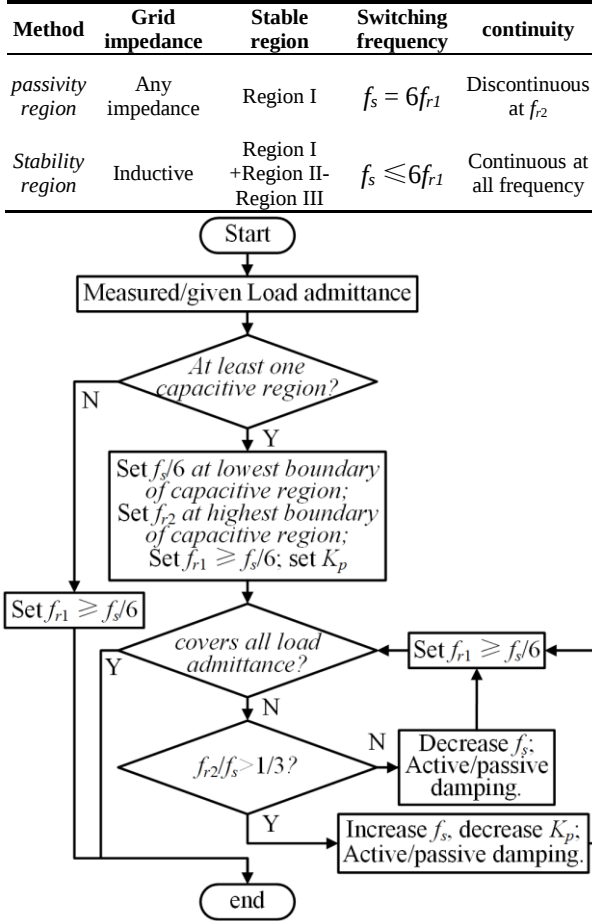


Fig. 11. Stability-oriented design of SAPF

D. Stability-oriented design

A comparison of these two methods is elaborated in Table I. As mentioned above, the grid impedance is mostly inductive, thus the stability region is easier to achieve because: 1. The stability region covers most of the passivity region and is beyond it, making it suitable for multi-capacitive region load; 2. The switching frequency f_s does not need to be equal to $6f_{r1}$; 3. The passivity region jumps at f_{r2} , while the stability region is continuous at any frequency.

A flow chart shown in Fig. 11 summarizes the stability-oriented design of SAPF based on the analysis above. First, the load admittance might be given or measured, which could be a specific curve or a region. If no capacitive region exists, the resonance frequency f_{r1} and f_{r2} can be designed according to other requirements and the switching frequency $f_{r1} \geq f_s/6$. Otherwise, set $f_s/6$ as the lowest boundary of the capacitive region and f_{r2} as the highest boundary of the capacitive region. K_p is determined by the current loop. After that, if the stability region does not cover load admittance at all frequencies, parameters should be adjusted to fit the phase of load admittance until the stability region covers load admittance at all frequencies.

When the frequency ratio f_{r2}/f_s is larger than $1/3$, the uncovered region appears above f_{r2} because the phase of $1+T_d(j\omega)$ might be smaller than -90° at this frequency range. Thus, the inductive region is not fully covered by the stability region. Switching frequency f_s can be increased to change the frequency ratio and proportional gain K_p can be decreased if the phase change of load at $f_s/6$ is slow. Moreover, active or passive damping should be adopted to suppress the phase jump. When the frequency ratio f_{r2}/f_s is smaller than $1/3$, the uncovered region appears at frequency smaller than f_{r2} because the phase of $1+T_d(j\omega)$ might be larger than 90 degrees at this frequency range. Therefore, decreasing the switching frequency or adding damping at f_{r2} can adjust the stability region to cover the load admittance.

IV. EXPERIMENTAL VALIDATION

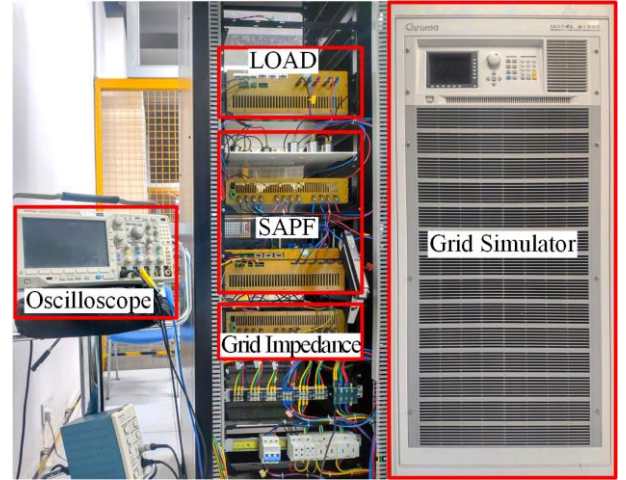


Fig. 12. A test platform.

TABLE II. PARAMETERS USED IN EXPERIMENTS

	Symbol	Meaning	Value
Base Case II	V_s	Grid voltage	190 V
	L_g	grid inductor	1.6 mH
	f_g	Grid frequency	50 Hz
	V_{dc}	DC-link voltage	400 V
	f_s	Switching frequency	4.28 kHz
	K_p	Proportional gain	18
	L_1	Converter side filter inductor	9.45 mH
	C_f	Filter Capacitor	5.26 μ F
	L_2	Grid side filter inductor	3.15 mH
	L_{1L}	Converter side filter inductor	9.45 mH
	L_{2L}	Grid side filter inductor	3.15 mH
	C_{fL}	Filter Capacitor	5.26 μ F
	I_{Lrms}	Load current (RMS)	3.6 A
	h	Harmonic order	5 th , 7 th
Modification Case I	C_f	Filter Capacitor (SAPF)	1 μ F
	K_p	Proportional gain	39
	f_s	Sampling frequency	10 kHz
Modification Case III	L_g	Grid inductor	3.2 mH
Modification Case IV	I_{Lrms}	Load current (RMS)	6 A
Modification Case V	f_s	Switching frequency	4.10 kHz
	C_{fL}	Filter Capacitor(load)	0 μ F

To verify the above analysis, the system depicted in Fig. 1 is established, and it is shown in Fig. 12. A Chroma 61800-series

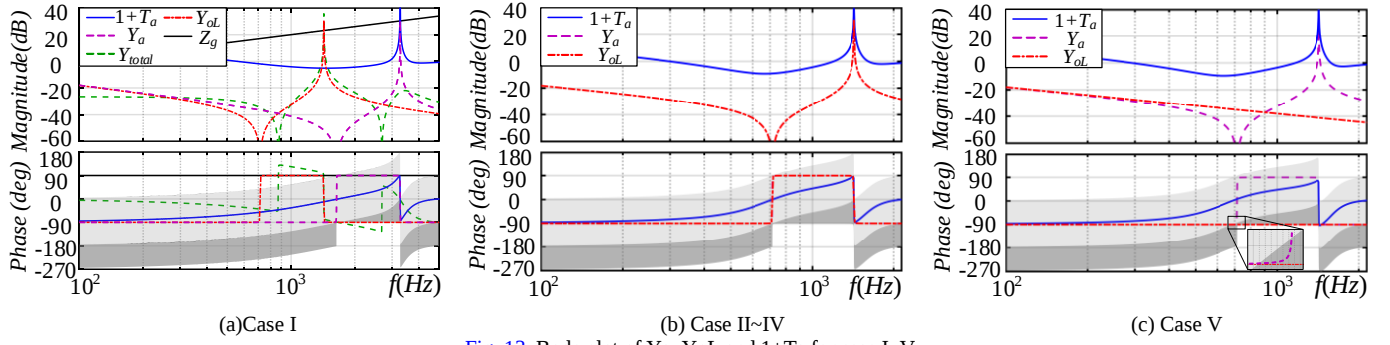
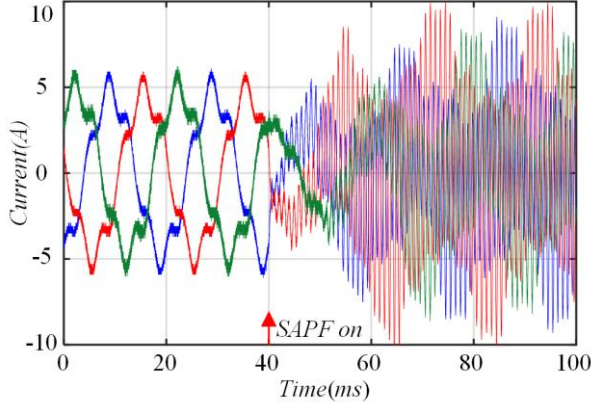
Fig. 13. Bode plot of Y_a , Y_{oL} and $1+T_a$ for case I~V

Fig. 14. Experimental grid current with parameters in Case I

ac power supply is used for emulating the grid. The grid impedance is inductive. A three-phase rectifier with open loop control and pulse width modulation in series with LCL filter is used to imitate a passive load, which behaves capacitive in a frequency range. The parameters of the test are listed in Table II.

As seen, five cases with different configurations of the system are tested. Case II is the base case. On top of it, the SAPF output admittance has a significant change in Case I; only the grid inductance changes in Case III; the load current is doubled in Case IV; the filter of load changes from LCL to L and the switching frequency is reduced in Case V.

Bode plot of Y_a , Y_{oL} and $1+T_a$, and the stability region are shown in Fig. 13. The phase of Y_a locates in the light shadow region (Region I) in Case I~IV. Therefore, if the load dynamic is ignored, the output admittance of SAPF $Y_a(s)/[1+T_a(s)]$ is passive. It means that these cases should be stable according to passivity criteria. However, the experimental result in Fig. 14 shows Case I loses stability once the SAPF is kicked in, which proves that the load dynamic in output admittance of SAPF cannot be ignored for stability analysis. The instability is also reflected by the bode plot in Fig. 13 (a), where $Y_{oL}(s)$ is out of the stability region.

In Case II, Y_{oL} is in the passivity region (region I), and the system is indeed stable after SAPF is kicked in, as shown in Fig. 15(a). On top of it, the grid inductance is doubled in Case III, and the load current is doubled in Case IV; however, they do not change the admittance of load or SAPF (seen Fig. 13 (b)), thus, the system is still stable (see Fig. 15 (b) and (d)). In Case V, the filter of the load is changed from LCL to L , and thereby the load admittance Y_{oL} changes, which is not covered by passivity region (region I) but stability region (region I + region II - region III),

as seen in Fig. 13 (c). In the end, the system is still stable (see Fig. 15 (c)), which again validates the stability region. It should be noted that $f_{r1} = f_s/6$ in Case II~IV, which is a condition of passivity region. Meanwhile the load admittance Y_{oL} indeed locates in the passivity region and the system is stable. In Case V, the switching frequency f_s is reduced, so $f_{r1} > f_s/6$. However, since the load admittance Y_{oL} is still in stability region, the system is still stable. As a result, both passivity and stability regions are validated. Further, $f_{r2}/f_s = 1/3$ in Case II~IV, but f_{r2}/f_s is slightly larger than $1/3$ in Case V. It proves that $f_{r2}/f_s = 1/3$ is not a strict condition for stability.

Additionally, the spectrums of grid currents are shown before and after the SAPF kicks in, as seen in Fig. 15 (a)~(c). The grid current harmonics are mainly at 5th and 7th. After the SAPF kicks in, the harmonics are significantly mitigated. A load change, which is essentially a transition from Case II to IV, is also demonstrated in Fig. 15 (d). As seen, the stability of the system is ensured during the transition. The dc side voltage of SAPF does not have significant dip, because SAPF only generates harmonic current, and the fundamental current is only used to compensate the power loss in the components. Thus there is no dramatic active power change in SAPF during load step

V. CONCLUSION

In this paper, an accurate admittance model for SAPF is developed. The coupling between SAPF and load is revealed, which shows a significant impact on the model. More importantly, based on the developed admittance model of SAPF, the stability region of the system is investigated. The passivity region of the load admittance to guarantee the system stability is firstly explored. However, the passivity region has rigorous boundary conditions, which are difficult to achieve in reality. The stability region is then studied, and it turns out to have much less strict boundary conditions, thereby much easier to fulfill. The stability region defined in this paper provides a guide to SAPF for valid application scenarios, where an accurate admittance model of the load is not required. Instead, more general knowledge of the admittance model (capacitive, inductive, or resistive) is sufficient to judge the stability of the system. The stability-oriented design is then summarized in a flow chart. In the end, the effectiveness of the newly defined stability region is verified by experimental results.

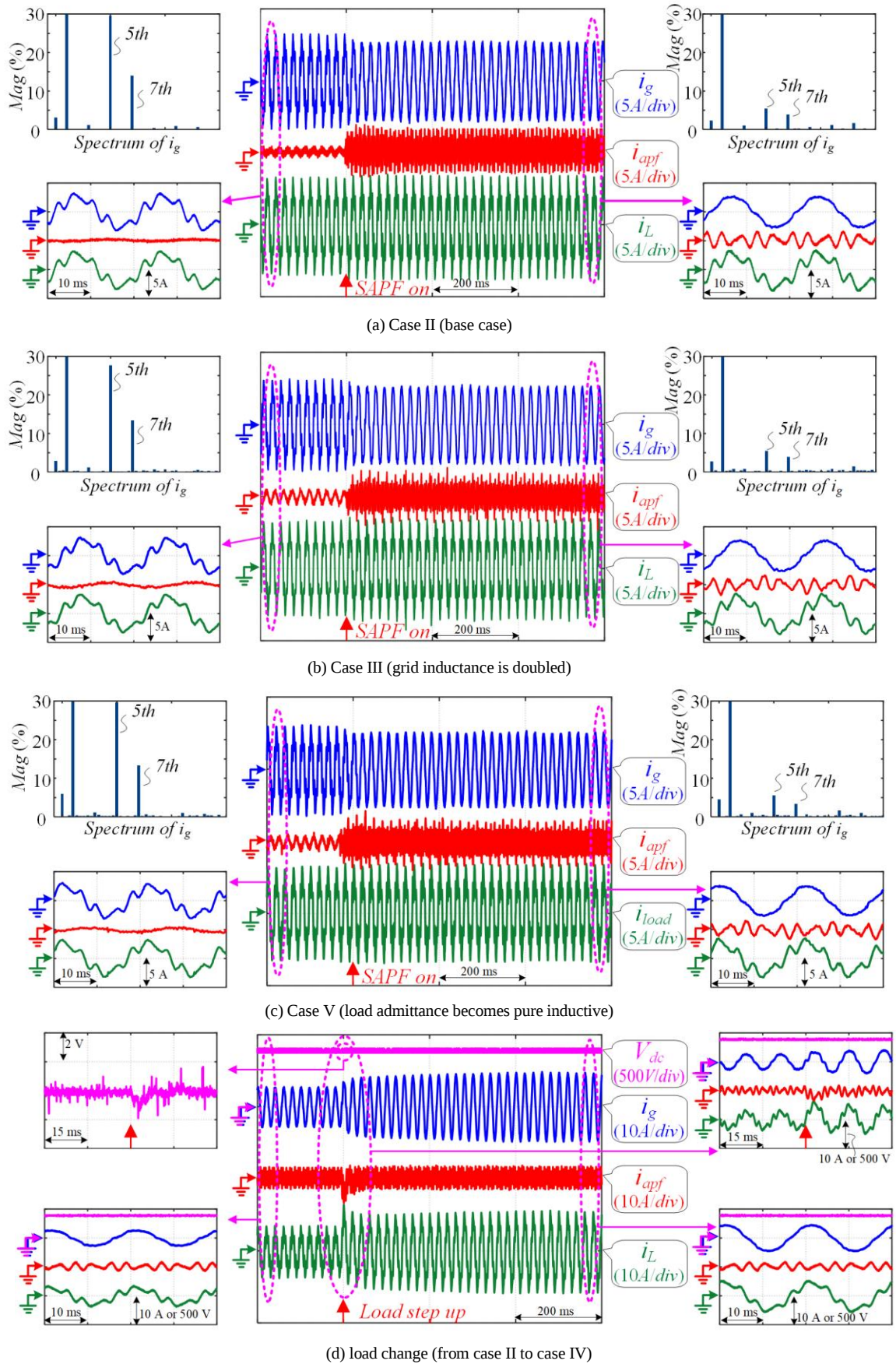


Fig. 15. Experimental results with SAPF kick in and load step to verify the stability region.

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